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Molybdenum disulfide nanoflakes through Li-AHA assisted exfoliation in aqueous medium

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Two dimensional materials are the promising candidates for sensing, catalysis, and energy storage applications because of their high surface area and excellent electronic properties. Layered materials such as graphite, transition metal dichalcogenides (TMDs) and transition metal oxides (TMOs) can be the major source of two dimensional systems. However, the development of two dimensional systems from the layered materials has been hindered by the lack of proper exfoliation technique. We report the exfoliation of bulk MoS₂ powder into few layered nanoflakes using lithium salt of 6-aminohexanoic acid (Li-AHA) in aqueous dispersion. Li-AHA treated MoS₂ was 'destacked' to form few layered nanoflakes due to the electrostatic repulsion. XRD analysis showed that the Li-AHA treatment resulted in the formation of highly crystalline MoS₂ nanoflakes. Raman spectroscopic analysis indicated a shift in E_{2g}¹ and A_{1g} peak suggesting the reduction in interlayer interaction, which in turn indicates the exfoliation. Electron microscopic observations strongly suggested the formation of few layered structure. These nanoflakes can be further incorporated into various polymer matrices to prepare composites with superior mechanical and electrical properties as compared to its bulk counterpart. The reported exfoliation technique is simple, effective and can be extended to exfoliate various transition metal dichalcogenides.

Introduction

Molybdenum disulfide (MoS₂), belonging to the family of layered transition metal dichalcogenides (TMDs), has been a subject of focused research in recent years due to its unusual structure and superior electrical, optical and mechanical properties. It is widely used as a solid lubricant^{1,2} in aerospace, military and also automotive applications. These layered materials are an important source for catalysis, sensing and energy storage applications. But the development of such materials has been limited because of the lack of a suitable liquid exfoliation method.³

The layered structure of MoS₂ crystallizes in hexagonal arrangement which consists of covalently bonded Mo and S atoms that gives rise to triple S-Mo-S sandwich layers. Such layers are stacked together by weak van der Waals forces. Hence the intra-layer bonding in MoS₂ is very strong as compared to the inter-layer bonding. The naturally occurring mineral form, 2H-MoS₂ has two layers possessing hexagonal symmetry in its unit cell. Each stable configuration of S-Mo-S layer is called 1H -MoS₂ monolayer. The bulk MoS₂ unit cell

belongs to space group P63/mmc and contains six atoms (two Mo and four S). The structure is uniquely determined by the hexagonal lattice constant *a*, the out-of-plane lattice constant *c*, and the internal displacement parameter *z*, whose experimental values were determined as, *a* = 3.16 Å, *c* = 12.58 Å, and *z* = 0.12.⁴

The recent discovery of graphene from graphite, a layered material, led to further exploration of 2D structures of layered materials. Such 2D materials are expected to be the forerunners in the future generation nanodevices owing to their exceptional carrier transport, ease of fabrication⁵ and tunable properties. The first report on the synthesis of inorganic fullerene-like MoS₂ based on the sulfidization of MoS₃ films by passing a stream of H₂S at elevated temperature (850–1050 °C) were made by Tenne and co-workers.⁶ Thereafter, various nanostructures of MoS₂ namely nanowires, nanotubes, nanorods, nanoflakes, nanoribbons, nanosheets, nanocrystals, nanofilms and nanofibers were fabricated.^{5,7–16} Different techniques such as hydrothermal route, direct reaction method, solid state reaction, electrochemical method, scotch tape method, sulfidation, chemical vapour deposition and electrospinning method were adopted to produce MoS₂ nanostructures. Monolayer MoS₂ exhibit diverse electronic,^{5,7} optical,^{8,9} mechanical,^{10,11} thermal,^{12,13} and chemical properties,^{14,15} fundamentally different from their bulk counterpart owing to quantum-mechanical confinement effect.¹⁶

In contrast to the zero-gap pristine graphene, the presence of a direct bandgap of 1.8 eV in monolayer MoS₂ allowed the

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fabrication of a room temperature current on/off transistor switch.⁵ This led to the inter-band tunnel FETs with lower power consumption, one of the crucial requirement in integrated circuits. Apart from being a solid lubricant, the 2D layered MoS₂ has been explored in the oil refining industry as hydro-treating catalyst,¹⁷ for reversible exchange of lithium in non-aqueous lithium batteries,^{14,18} new generation transistors,⁵ electrochemical hydrogen storage,^{15,19} DNA hybridization detection,²⁰ biosystems,²¹ photovoltaic solar cells,²² as nanocomposites,^{23,24} nanotribology,²⁵ and also to achieve spintronic and valleytronic effect.²⁶ These results are intriguing, which realizes the 2D mono and multi layered MoS₂ as an appealing material in next generation devices.

Several techniques have been employed for the exfoliation of MoS₂ into a few layered nanoflakes-structure. The weak interlayer interaction and a large separation of 0.615 nm between MoS₂ layers enable the intercalation and easy diffusion of the Li ions without much change in the volume. It was envisaged that the exfoliation of MoS₂ into separate layers was obtained by the charge transfer to the MoS₂ layers after the insertion of lithium atoms between these layers followed by the hydration of the resulting LiMoS₂. However, the chemical exfoliation of MoS₂ through Li intercalation followed by ultra-sonication in aqueous medium results in significant deviation from the hexagonal structure.^{27,28,29} Obtaining stable structures of few layer MoS₂ nanoflakes with beyond 10⁵ atoms is a real challenge, because such layers scroll up to nanotubes and quasi spherical nanoparticle inorganic fullerene like nanoparticles.³⁰ Coleman et al. have used a number of common solvents to estimate their suitability for exfoliation of bulk TMDs through ultrasonication.³ On analyzing the liquid exfoliated few layer MoS₂, it was found to possess hexagonal structure. MoS₂ nanosheets with controllable morphologies have been synthesized by mixed-solvothermal method. The organic solvents were adhered to the surface of MoS₂ and the different absorbing effect of the two mixed-solvents on MoS₂ surfaces resulted in the formation of different morphologies.³¹ Mechanical exfoliation using scotch-tape has produced single layer MoS₂ which showed an excellent photo responsivity as compared to the graphene-based device.³² Jian Zhen Ou et al. fabricated quasi 2D- MoS₂ nanoflakes from MoS₂ bulk powder using a grinding-assisted liquid phase exfoliation technique.³³ Recently Clark et al. reported green synthesis technique for MoS₂ nanoflakes using chenodeoxycholic acid as surfactant, which resulted in high yields.³⁴ The use of various surfactants in exfoliating MoS₂ has been extensively reported.^{24,35–37} A scalable 2D spatial confinement technique has been developed for in situ synthesis of few layered and highly crystalline MoS₂ nanosheets anchored on 3D porous carbon nanosheet networks.³⁸

Sodium salt of 6-aminohexanoic acid (Na-AHA) have been employed to improve the dispersion state of multiwalled carbon nanotubes in various polymer matrices.^{39,40} Non-covalent modification of expanded graphite (EG) with lithium salt of 6-aminohexanoic acid (Li-AHA) led to the exfoliation of EG and formed a few layer 'graphene-like' structure.⁴¹ Such

non-covalent surface modification is of particular interest because it enhances the dispersibility and do not alter the inherent properties of the carbon nanostructures.⁴² It is reported that Na-AHA molecules were adsorbed on carbon nanotubes surface and facilitate the "debundling" of nanotube agglomerates through electrostatic charge repulsion and steric stabilization.³⁹ These organic molecules based on 6-aminohexanoic acid facilitate the 'de-agglomeration' of carbon nanotubes and 'de-stacking' of EG through the electrostatic repulsive forces due to the formation of electrical double layer in aqueous dispersion.^{39–41}

Owing to its hydrophobic nature, exfoliating MoS₂ in water is challenging. Alkali lignin assisted exfoliation is one of the first studies on liquid-phase exfoliation of MoS₂ based on aqueous media.⁴³ Nanofibrillated cellulose has been used to produce water-based dispersions of MoS₂.⁴⁴ In this work we report a new route to produce few layer MoS₂ nanosheets through Li-AHA assisted liquid phase exfoliation of bulk MoS₂ powder in aqueous medium. The role of Li-AHA modifier in exfoliating MoS₂, its interaction with MoS₂ surface and the mechanism of exfoliation are discussed. This route permits the synthesis of few layer MoS₂ from bulk crystalline MoS₂ and it was envisaged that specific interaction between Li⁺ ions of the modifier and the d-electron clouds of MoS₂ would lead to significant debundling of the MoS₂ layers. Moreover, the proposed exfoliation technique does not require high temperature treatment or any organic solvents and hence is a green synthesis route. This method can be employed as an alternative route to exfoliate other TMDs.

Experimental details

Materials

Lithium hydroxide (LiOH) (Sigma Aldrich, purity: 98%), 6-amino hexanoic acid (AHA) (Sigma Aldrich, Mw= 132.18; purity: 98%) and commercially available Molybdenum disulfide powder (LOBA Chemie, purity: 98%) are the materials used in the present work.

Exfoliation of MoS₂

6-aminohexanoic acid was neutralized using Lithium hydroxide to obtain Li-AHA. MoS₂ was treated with 1:1 (wt/wt), 1:2 (wt/wt) and 1:4 (wt/wt) of Li-AHA in order to understand the influence of Li-AHA concentration on the extent of exfoliation. The amount of MoS₂ was kept constant and the percentage of Li-AHA was varied to achieve different modifier concentrations. Bulk MoS₂ powder was initially dispersed in distilled water by ultra-sonication (probe type ultrasonic processor DP120, frequency 50 kHz) for 10 min. The required amount of Li-AHA was dissolved in deionized water and the solution was then added to the MoS₂ dispersion and further ultra-sonicated for 30 min. Subsequently, the dispersion was continuously heated and stirred over a hot plate to obtain a dry mixture of Li-AHA treated MoS₂. Further, the treated MoS₂ was dried under vacuum at 75 °C overnight to remove traces of water. Also, bulk MoS₂ was sonicated in deionized water for

the same duration (hereafter denoted as untreated MoS₂) to identify whether ultra-sonication could cause any exfoliation even in the absence of Li-AHA.

Characterization

X-ray diffraction (XRD) studies were carried out on a Philips X-Pert Pro. The incident X-rays ($\lambda=1.54 \text{ \AA}$) from the Cu-target were monochromatized using a Ni filter. XRD patterns were recorded with a step scan with step size of 0.02 between 5° and 70° (2 θ).

Raman spectroscopic analysis was done using a HR 800 micro-Raman (HORIBA Jobin Yvon, France) for bulk, untreated and Li-AHA treated MoS₂ in the scanning range of 250 to 500 cm⁻¹ with an incident laser of excitation wavelength 514 nm.

Scanning electron microscopic (SEM) analysis was carried out using an FEG-SEM (JSM-7600F, Japan) with an accelerating voltage of 10 kV. To prepare the samples for SEM analysis, a small quantity of bulk/ Li-AHA treated MoS₂ was dispersed in de-ionised water and a drop was placed on Si wafer and was then dried. Silicon wafer containing the dried MoS₂ sheets was then gold sputtered to obtain the micrographs.

The transmission electron microscopic (TEM) analyses were carried out on a JEOL JEM-2100 F, Japan, field emission electron microscope. To prepare the samples for TEM investigation, MoS₂ powder was dispersed in de-ionised water, and a drop of the dispersion was placed on the TEM grid, after which it was dried. Selected area electron diffraction (SAED) analysis was used to determine the crystalline morphology associated with MoS₂ layer during TEM investigation.

Results and discussion

XRD analysis of bulk MoS₂ and Li-AHA treated MoS₂

The XRD pattern of bulk MoS₂ and various Li-AHA treated MoS₂ are shown in fig. 1. The characteristic peaks of (002), (100), (102), (103), (006), (105), (110) and (112) appearing at 2 θ =14.5, 32.8, 36.1, 39.8, 44.3, 50.06, 58.4 and 60.5 confirms 2H-MoS₂ with lattice constants $a = 3.1616 \text{ \AA}$ and $c = 12.2985 \text{ \AA}$ (JCPDS 37-1492).⁴⁵ The (002) peak indicates the stacking of single layers, whereas the set of higher angle peaks could provide information about the crystallinity within the layers.⁴⁶ At reflection 2 θ =14.5°, corresponding to (002) peak of untreated MoS₂, the d-spacing is calculated to be 0.615 nm and it matches with the reported value of 2H-MoS₂.⁴⁷ It is noticed that the intensity of (002) diffraction peak of the Li-AHA treated MoS₂ decreases as compared to the untreated and it indicates the de-stacking of MoS₂ layers. Furthermore, there is a marginal shift to lower angles for (002) peaks of Li-AHA treated with respect to that hexagonal 2H-MoS₂ phase (a maximum shift of ~1.5 % for 1:4 Li-AHA treated MoS₂). The shift in the (002) peaks to lower angles suggests the lattice expansion along the c-axis for the introduction of crystal defects or strains owing to curvature of the layers.^{31,37} The

marginal shift signifies that the lattice distortion is minimal after the exfoliation and hence the structure is relaxed. The (002) peak shift and variation in intensity are illustrated as inset in fig 1. The decrease in (002) peak intensity suggests the reduction in thickness of bulk MoS₂ flakes.⁴⁸ The strong (103) peaks for the Li-AHA treated samples reveals the highly crystalline nature¹⁸ and this implies that the inlayer crystallinity of Li-AHA treated MoS₂ is significantly improved. Hence, the XRD observations imply that the Li-AHA

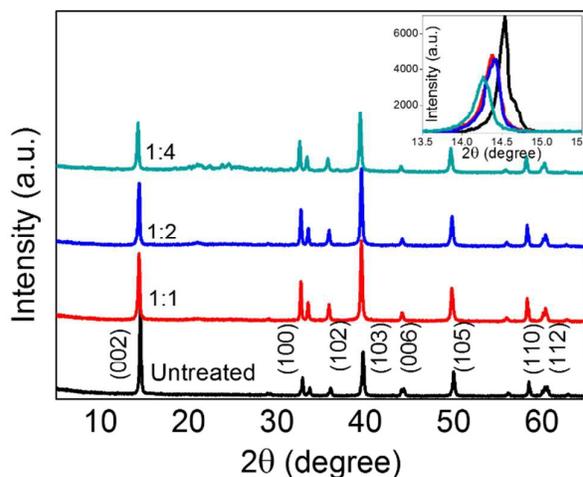


Fig. 1 XRD spectra of untreated and Li-AHA treated MoS₂

assisted liquid phase exfoliation is effectively de-stacking the bulk MoS₂ flakes.

Raman spectroscopic analysis of bulk, untreated and Li-AHA treated MoS₂

Raman spectroscopy is the most powerful non-destructive technique for the identification of 2D MoS₂ materials since the shift in prominent peak position and line width could provide information about the structure of the material. Fig. 2 shows the Raman spectra of bulk, untreated and Li-AHA treated MoS₂. The bulk MoS₂ shows two well defined peaks at 402 cm⁻¹ and 376 cm⁻¹ which are assigned to high energy A_{1g} and lower energy E_{2g}¹ vibrational modes respectively,^{49,50} and are separated by $\Delta=26 \text{ cm}^{-1}$. The E_{2g}¹ mode signifies the in-layer displacements of Mo and S atoms and the A_{1g} mode represents the out-of-layer displacements of S atoms along the c-axis.⁵¹ It is observed that there is no significant variation in peak values for the bulk and untreated MoS₂.

The spectra demonstrate that there is a significant blue shift in the E_{2g}¹ and A_{1g} peaks of Li-AHA treated MoS₂ with respect to the bulk/untreated MoS₂. This observation is in direct contrast to most of the previous experimental studies on the MoS₂ material. Typically, in the exfoliated MoS₂ nanosheets the A_{1g} mode exhibits red-shift due to the decreased interlayer van der Waals force and the E_{2g}¹ mode exhibits blue-shift due to the long-range Coulombic interlayer interactions.^{52,53} However, the MoS₂ nanosheets produced by chemical-assisted exfoliation exhibited red-shift of E_{2g}¹ mode and it was attributed to the adsorption of surfactants,

intercalation agents or solvents on the surface of the MoS₂ nanosheets.^{43,54–56} Furthermore, the experimental studies on exfoliation of analogous WS₂ material showed a blue-shift of both the E_{2g} and A_{1g} peaks upon exfoliation to single layered material.⁵⁷

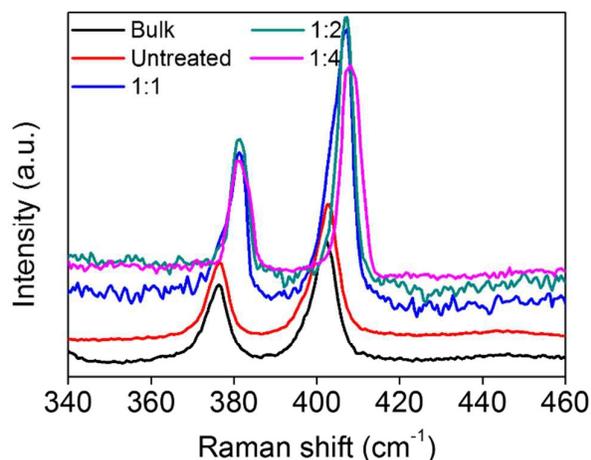


Fig. 2 Raman spectra of bulk, untreated, Li-AHA treated MoS₂

Change in the peak position could be investigated on the basis of resonance due to electronic and vibrational densities of state.⁴⁰ A considerable amount of blue shift (max. of ~ 6.2 cm⁻¹) is observed for the Li-AHA treated samples with respect

to the bulk MoS₂. The reduction of the interlayer interaction for the exfoliated particles could lead to the observed shift to higher wave number at a constant laser excitation, indicating the “de-stacking” of MoS₂ layers. The vibrational densities of state may vary due to the adsorption of the Li-AHA molecules on MoS₂ surfaces, which may alter the vibrational modes of MoS₂. We believe that the surface modification of MoS₂ nanosheets by the adsorbed Li-AHA molecules could be the reason for the unusual blue shift of both the E_{2g}¹ and A_{1g} peaks. Furthermore, the intensity of the peaks for Li-AHA treated MoS₂ are relatively higher and broader indicating the reduction in the thickness of bulk MoS₂ flakes.^{55,57}

SEM analysis: Morphology of untreated and Li-AHA treated MoS₂

Fig. 3 shows the morphology of untreated and Li-AHA treated MoS₂. The SEM images give an insight into the exfoliation of untreated MoS₂ before and after Li-AHA intercalation. Fig. 3(a-c) clearly illustrates the multi layered structure of untreated MoS₂ and it is evident from the micrographs that the untreated MoS₂ exhibits a larger thickness. The SEM micrographs for 1:1 Li-AHA treated MoS₂ exhibits nanosheet morphology; a well dispersed and much thinner flakes could be seen Fig. 3(d-f). We attribute this effect to the exfoliation of MoS₂ in the presence of Li-AHA. Fig. 3(g-i) and fig. 3(j-l) shows the SEM images for 1:2 and 1:4 Li-AHA treated MoS₂. It is seen that many irregular layers of MoS₂ assemble to form floral structure for 1:2 Li-AHA treated MoS₂.

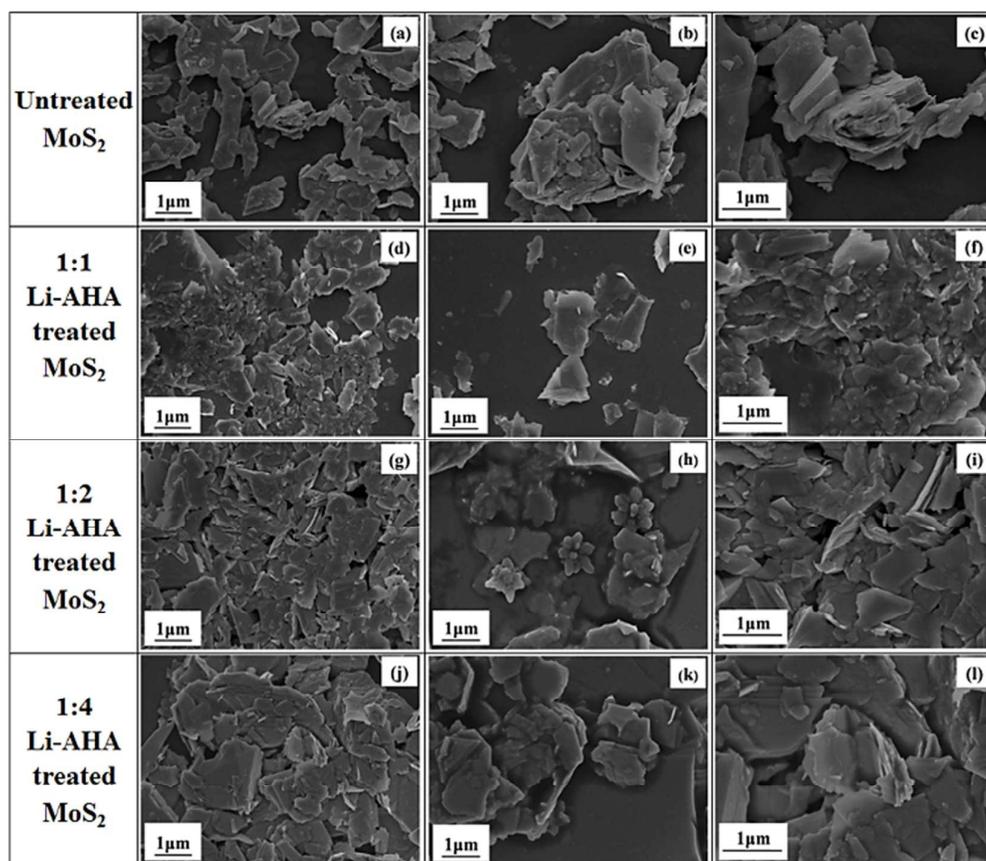


Fig. 3 SEM images of untreated and Li-AHA treated MoS₂ at 10000X, 15000X and 25000X magnifications: (a)-(c) untreated MoS₂; (d)-(f) 1:1 Li-AHA treated MoS₂; (g)-(i) 1:2 Li-AHA treated MoS₂; (j)-(l) 1:4 Li-AHA treated MoS₂

It is observed that the 'de-stacked' flakes forms clusters for higher Li-AHA concentration and also Li-AHA get adsorbed on the surface of MoS₂ nanosheets (fig. 3 (j-l)). The surface coverage of Li-AHA on MoS₂ nanoflakes could be advantageous as the aminemoiety on Li-AHA can act as a surface functionality and improves the interfacial interaction in various polymer matrices in case if this nanoflakes are further used to prepare polymer composites. The Li-AHA treatment led to the exfoliation of MoS₂ and forms the few layer nanoflakes. However, the Li-AHA concentration must be optimized to obtain an effective exfoliation.

TEM analysis - Morphology of untreated and Li-AHA treated MoS₂ & Identification of few layered structure using SAED

TEM and SAED analysis depicts the quantitative evidence for the exfoliation of untreated MoS₂ upon treating with Li-AHA. It is apparent from the TEM images that the Li-AHA treated MoS₂ has undergone an effective exfoliation and nanoflakes of a few layer MoS₂ are formed. It is observed that the nanosheets are slightly transparent to the electron beam, which indicates their ultrathin structure. Morphological investigation of untreated MoS₂ shows the layered 'platelet-like' structure with varying layer thickness and size for different platelets. The larger thickness of untreated MoS₂ flakes are evident from the SEM and TEM micrographs. The SAED analysis of untreated MoS₂ depicts a 'ring-like' pattern which indicate its 'polycrystalline' nature. On the other hand, all the Li-AHA treated samples exhibit 'hexagonal' dot pattern in the SAED analysis,

confirming the exfoliation of bulk MoS_2 into few layer nanosheets.

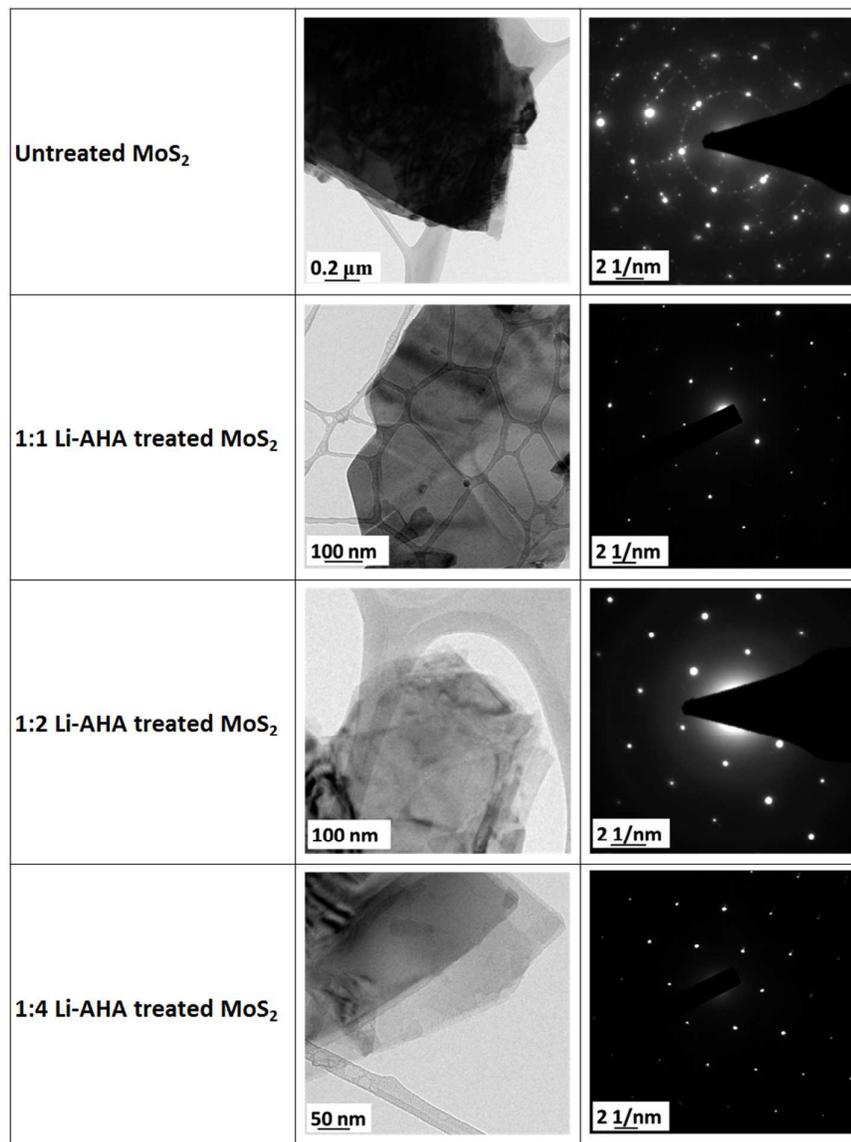


Fig. 4 TEM images and SAED patterns of untreated and Li-AHA treated MoS_2

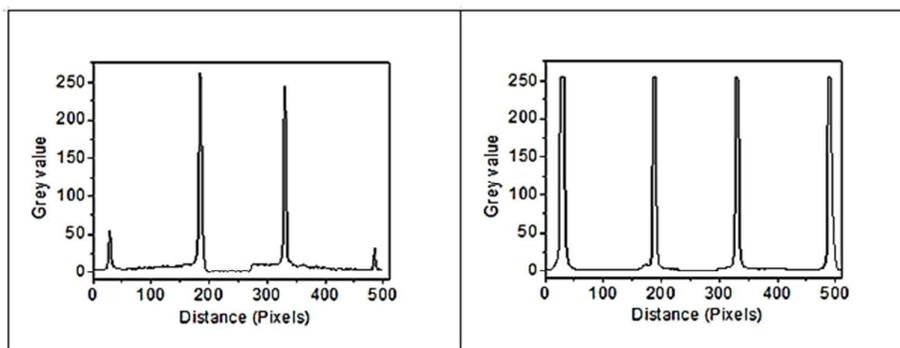


Fig. 5 The intensity profile for the 1:1 and 1:4 Li-AHA treated MoS_2

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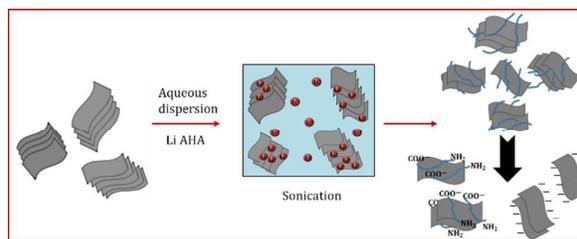
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Furthermore, 1:1 Li-AHA concentration lead to the significant exfoliation as compared to the higher Li-AHA concentrations. The SAED pattern can also be used to distinguish between single and few layer MoS₂ by comparing the spot intensity profile of two adjacent planes in the hexagonal dot pattern. Single layer 2D material gives higher spot intensity for inner plane compared to outer plane, whereas a few-layer flake gives higher intensity for outer layer compared to inner layer.^{58,59} Hence, the ratio of inner plane to outer plane spot intensity, I_R is greater than 1 for monolayer structure and less than 1 for a few layer structure. Fig. 5 illustrates the SAED analysis carried out for 1:1 and 1:4 Li-AHA treated MoS₂. It is seen that $I_R > 1$ for 1:1 Li-AHA content, which suggests the inner reflections are intense as compared to the outer reflection, confirming that the sample is consistent with isolated single layer structure. On the other hand, I_R is marginally less than 1 for 1:4 Li-AHA content, indicating a few layer structure of exfoliated MoS₂. Hence it is understood that exfoliation of MoS₂ with Li-AHA at appropriate concentration can yield monolayer flakes.

The MoS₂ platelets are stacked together by weak van der Waals forces and hence the inter-layer bonding is very weak as compared to the intra-layer covalent bonding in MoS₂. Li-AHA treated MoS₂ has been 'exfoliated' or 'destacked' to form a few layer nanoflakes due to the electrostatic repulsion, similar to the observation reported in the case of multiwalled carbon nanotubes and EG. Li-AHA on dissociation leads to Li⁺ and AHA⁻ in deionized water. The weak interlayer interaction and large separation distance between the MoS₂ layers enable intercalation and easy diffusion of the Li⁺ ions into the MoS₂ gallery. During ultra-sonication, the intercalated Li⁺ ions could expedite the exfoliation of 'stacked' MoS₂ in the aqueous medium. Furthermore, the extended 'destacking' of MoS₂ platelets into a few layer nanoflakes in the presence of Li-AHA may be rationalized by the electrostatic charge repulsion between the negative charges due to the formation of an electrical double layer in aqueous dispersion. It could be explained in line with the exfoliation mechanisms postulated in case of debundling of nanotubes and exfoliation of EG.^{39,41} The AHA⁻ could enter into the aggregates of MoS₂ stacks and break them up under ultra-sonication. Initially, the MoS₂ aggregates debundle due to the adsorption and intercalation of the modifier ions on the MoS₂ aggregates and gallery. Furthermore, these modifier molecules stabilize the dispersion through the electrostatic charge repulsion.

In aqueous solution, the MoS₂ surface is negatively charged due to the adsorbed AHA⁻ groups, whereas Li⁺ ions may move throughout the aqueous medium and also intercalate in between the MoS₂ layers. The Li⁺ ions may partly shield the

negative charges on the MoS₂ surface and lead to the formation of an electrical double layer at MoS₂ surface with net negative charge. Subsequently, this leads to the stabilization of dispersed MoS₂ nanoflakes since the energy barrier for the 'restacking' of MoS₂ layers might be very high. Scheme 1 schematically illustrates the exfoliation mechanism of bulk MoS₂. Hence the exfoliation of bulk MoS₂ in to the few layer nanosheets can be envisaged as a synergistic effect of electrostatic repulsion due to the electrical double layer formation and the intercalation of Li⁺ ions in to the MoS₂ gallery.



Scheme 1. Schematic showing the exfoliation mechanism of Li-AHA treated MoS₂ in deionized water

Conclusions

In brief, we have established that Li-AHA can be effectively used for the exfoliation of MoS₂. Three different Li-AHA concentrations have been tried to understand the influence of Li-AHA concentration on the extent of MoS₂ exfoliation. SEM and TEM analysis along with Raman Spectroscopic analysis and XRD indicated the exfoliation of MoS₂ into few layered nanoflakes. It was understood that well dispersed nanoflakes were obtained for 1:1 (wt/wt, MoS₂: Li-AHA) concentration. The reported exfoliation technique is simple and effective. Furthermore, we believe it is a general technique and can be extended to exfoliate various transition metal dichalcogenides and other layered materials.

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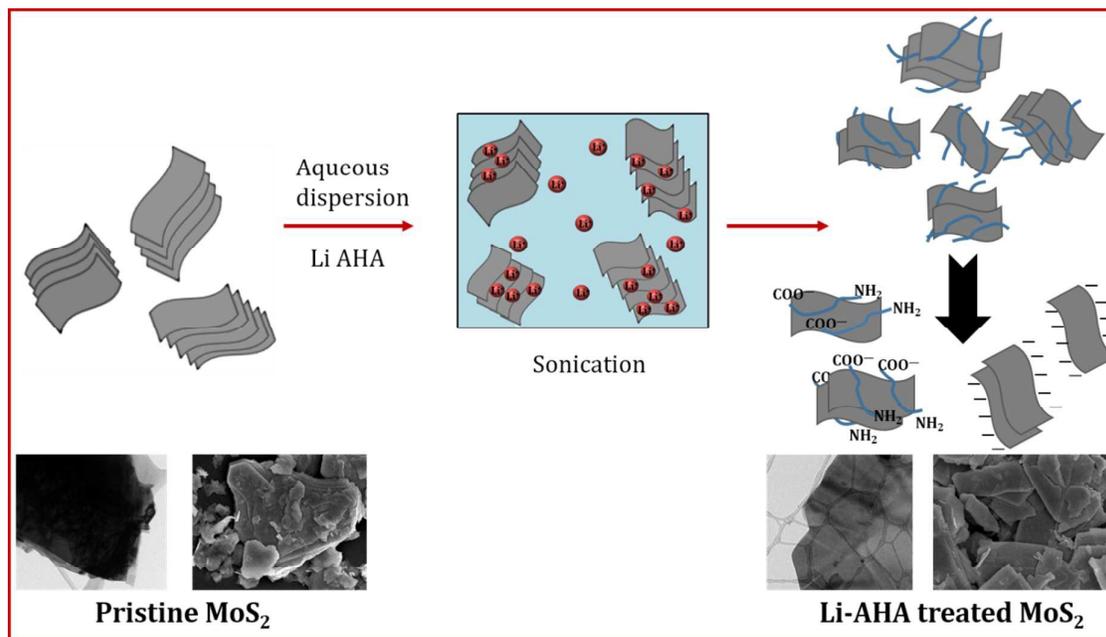
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A novel route to synthesize MoS₂ nanoflakes through Li-AHA assisted liquid phase exfoliation